

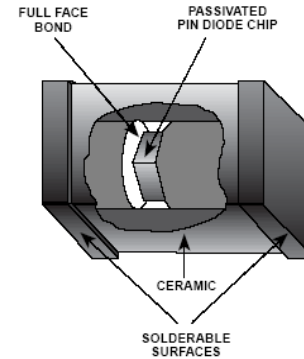
Features

- Non-Magnetic Package Suitable for MRI Applications
- Rectangular MELF SMQ Ceramic Package
- Hermetically Sealed
- Low R_s for Lower Series Loss
- Long τ_L for Low Intermodulation Distortion
- Low C_j for High Series Isolation
- High Average Incident Power Handling Capability

Description and Applications

The MA4P7470F-1072T is a surface mountable PIN diode in a non-magnetic Metal Electrode Leadless Faced (MELF) package. The device incorporates M/A-COM's time proven HIPAX technology to produce a low inductance ceramic package with no ribbons or whisker wires. The package utilizes M/A-COM's new non-magnetic plating process to provide an extremely low permeability, hermetically sealed package. Incorporated in the package is a passivated PIN diode that is full face bonded on both the cathode and anode of the chip to maximize surface area for low electrical and thermal resistance. The MA4P7470F-1072T has been comprehensively characterized both electrically and mechanically to ensure repeatable and predictable performance. This MA4P7470F-1072T non-magnetic device is similar in electrical performance to the MA4P7417F-1072T magnetic part number.

The diode is well suited for use in low loss, low distortion, and high power switching circuits applicable for high magnetic field environments from HF through UHF frequencies. The lower thermal resistance of this device provides excellent higher average performance at RF power incident levels up to 200 watts CW. This device is designed to meet the most rigorous electrical and mechanical requirements of MRI testing environments.



Designed for Automated Assembly

These SMQ PIN diodes are designed for high volume tape and reel assembly. The rectangular package design provides for highly efficient automatic pick and place assembly techniques. The parallel flat surfaces are suitable for key jaw or vacuum pickup techniques. All solderable surfaces are tin plated and compatible with reflow and vapor phase soldering methods.

Absolute Maximum Ratings¹ @ +25°C

Parameter	Absolute Maximum
Operating Temperature	-65°C to +125°C
Storage Temperature	-65°C to +150°C
Diode Junction Temperature	+175°C Continuous
Diode Mounting Temperature	+265 °C for 10 seconds
RF C.W. Incident Power	+ 53dBm C.W.
Forward D.C. Current	+ 150mA
Reverse D.C. Voltage @ -10 uA	- 800V

1. Exceeding these limits may cause permanent damage.

Environmental Capability

HIPAX devices are applicable for use in industrial and military applications and can be screened to meet the environmental requirements of MIL-STD-750, MIL-STD-202 as well as other military standards. The table below lists some of the MIL-STD 750 tests the device is designed to meet.

MIL-STD-750		
Test	Method	Description
High Temperature Storage	1031	+150 °C, for 340 Hours
Temperature Shock	1051	-65 °C to +125 °C, 20 Cycles
HTRB	1038	80% of rated V_B , +150 °C, for 96 Hours
Moisture Resistance	1021	No Initial Conditioning, 85 % RH, +85° C
Gross Leak	1071 Cond. E	Dye Penetrant Visual
Vibration Fatigue	2046	20,000 G's, 60 Hz, x, y, z axis
Solderability	2026	Test Temperature = +245 °C

Ordering Information

Part Number	Package
MA4P7470F-1072T	Tape and Reel

Electrical Specifications @ +25 °C

Parameter	Symbol	Condition	Unit Value
Forward Voltage (Maximum)	V_F	$I_F = +100\text{mA}$	$1.0V_{DC}$
Voltage Rating (Minimum)	V_R	$I_r = -10\mu\text{A}$	$I - 800 I V_{DC}$
Total Capacitance (Maximum)	C_T	$-100\text{V @ } 100\text{MHz}$	0.7pF
Series Resistance (Maximum)	R_S	$+100\text{mA @ } 100\text{MHz}$	0.8 Ohms
Parallel Resistance (Minimum)	R_P	$-10\text{V @ } 100\text{MHz}$	$50\text{K } \Omega$
Carrier Lifetime (Nominal)	τ_L	$+6\text{mA} / -10\text{mA @}$ $(50\% - 90\% \text{ Voltage})$	$6.5 \mu\text{s}$
I-Region Length (Nominal)	μm	-	$140 \mu\text{m}$
C.W. Thermal Resistance (Maximum)	θ	$I_H = 1\text{A}, I_L = 10\text{mA},$ $T = 1\text{mS}$	13°C/W
Power Dissipation in Free Air (Maximum)	W	$I_F = +100\text{mA}$	4W
Power Dissipation with Diode Case at Tambient (Maximum)	P_D	$I_F = +100\text{mA}$	12W

MA4P7470F-1072T

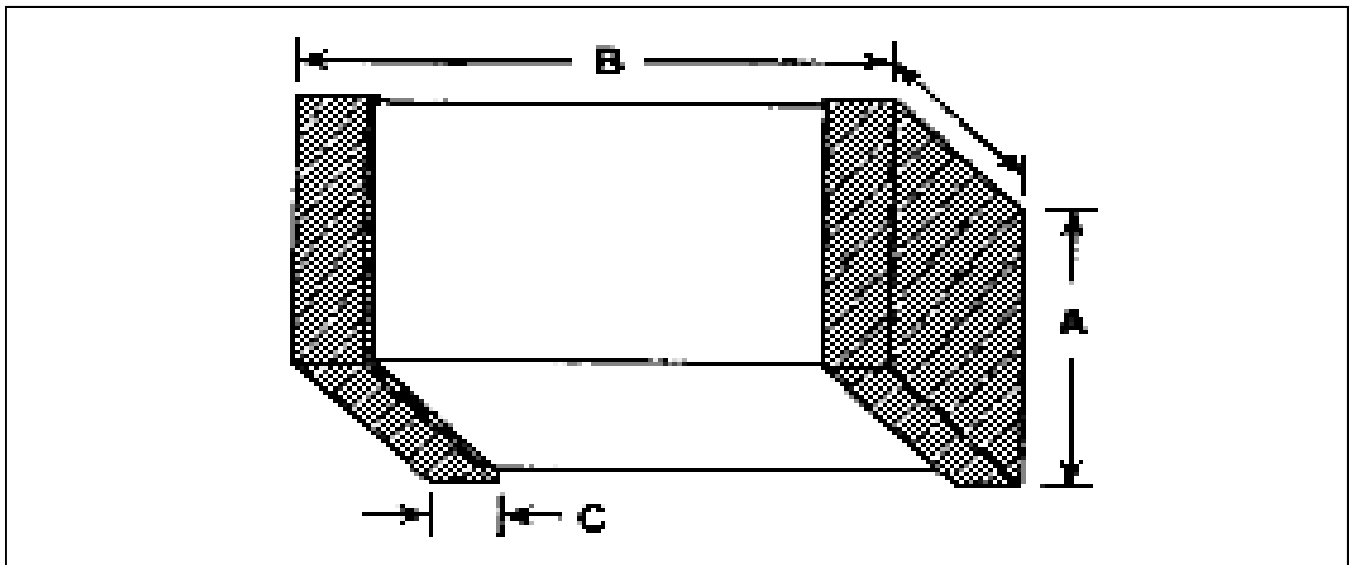


2000 Volt & 3000 Volt PIN Diodes
 MA4PK2000, MA4PK3000

Rev. V2

Mechanical Outline

Case Style	Dimensions in Inches (mm)		
	A Square Min / Max	B Min / Max	C Min / Max
1072	0.080 / 0.095 (2.03 / 2.41)	0.115 / 0.135 (2.92 / 3.43)	0.008 / 0.030 (.203 / .762)



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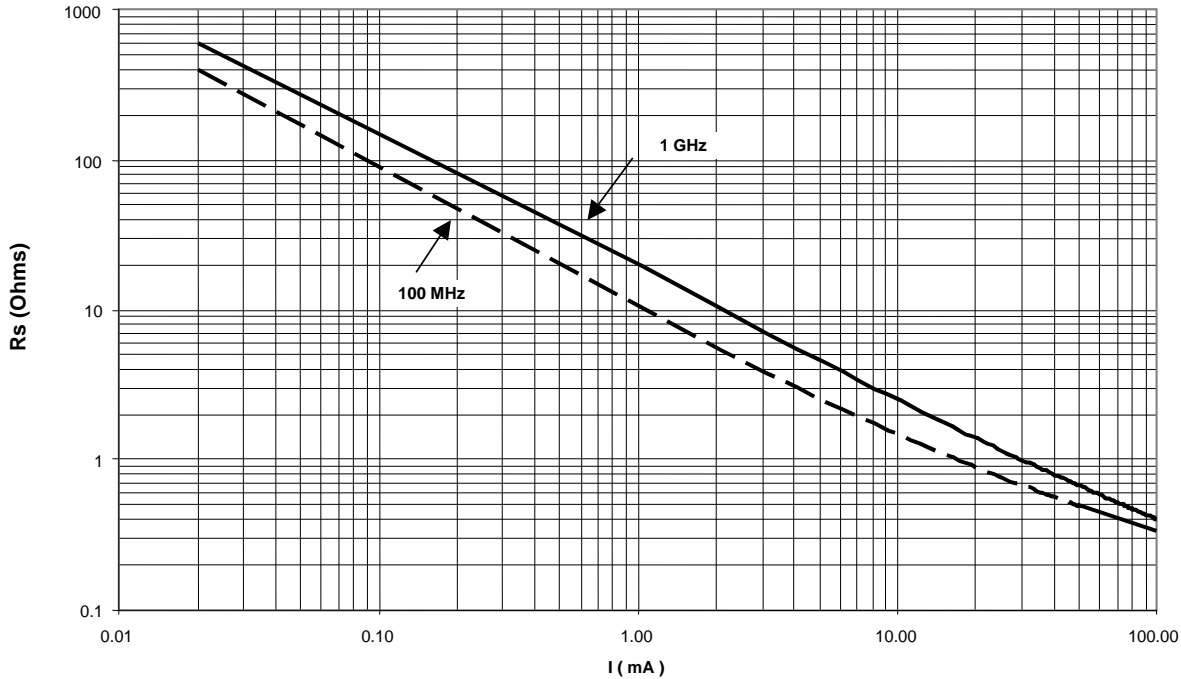
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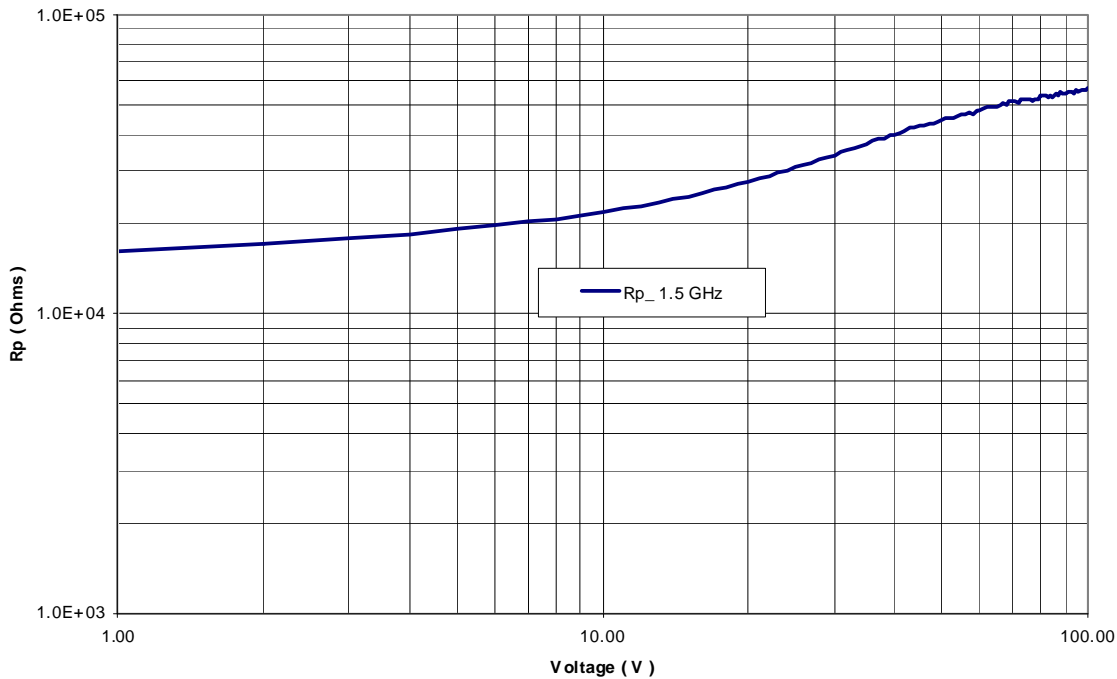
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Typical Electrical Performance

MA4P7470F-1072T Rs vs I

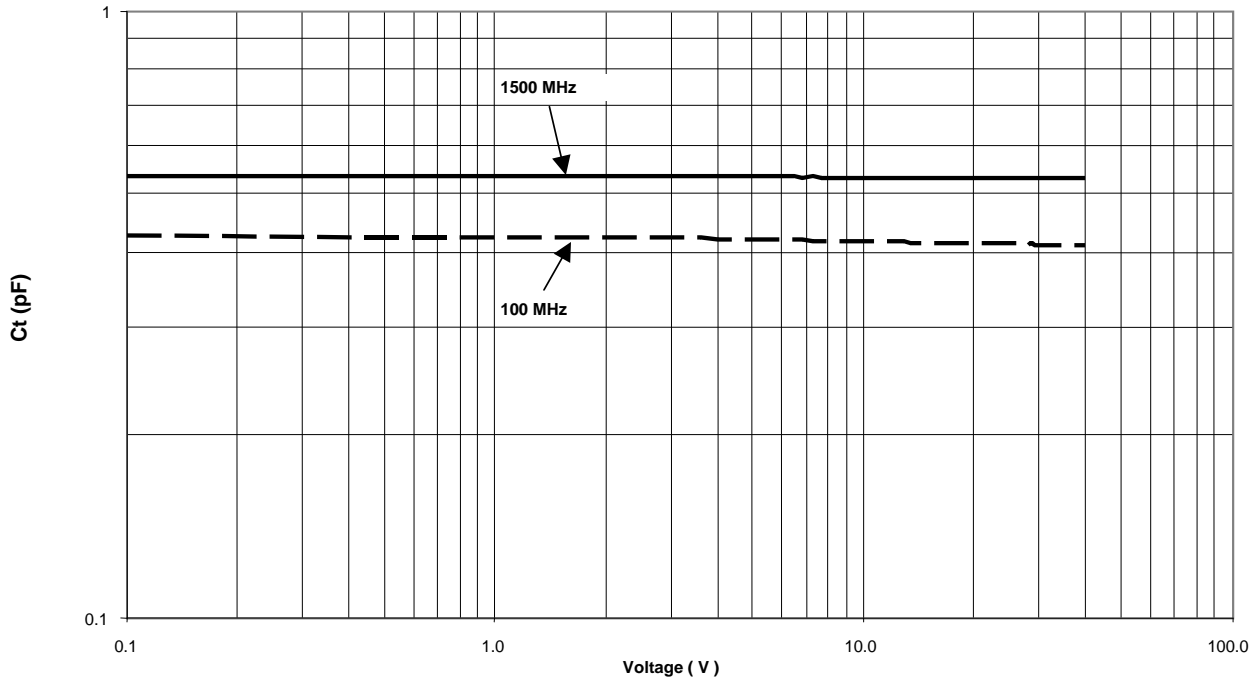


MA4P7470F-1072T Rp vs Voltage

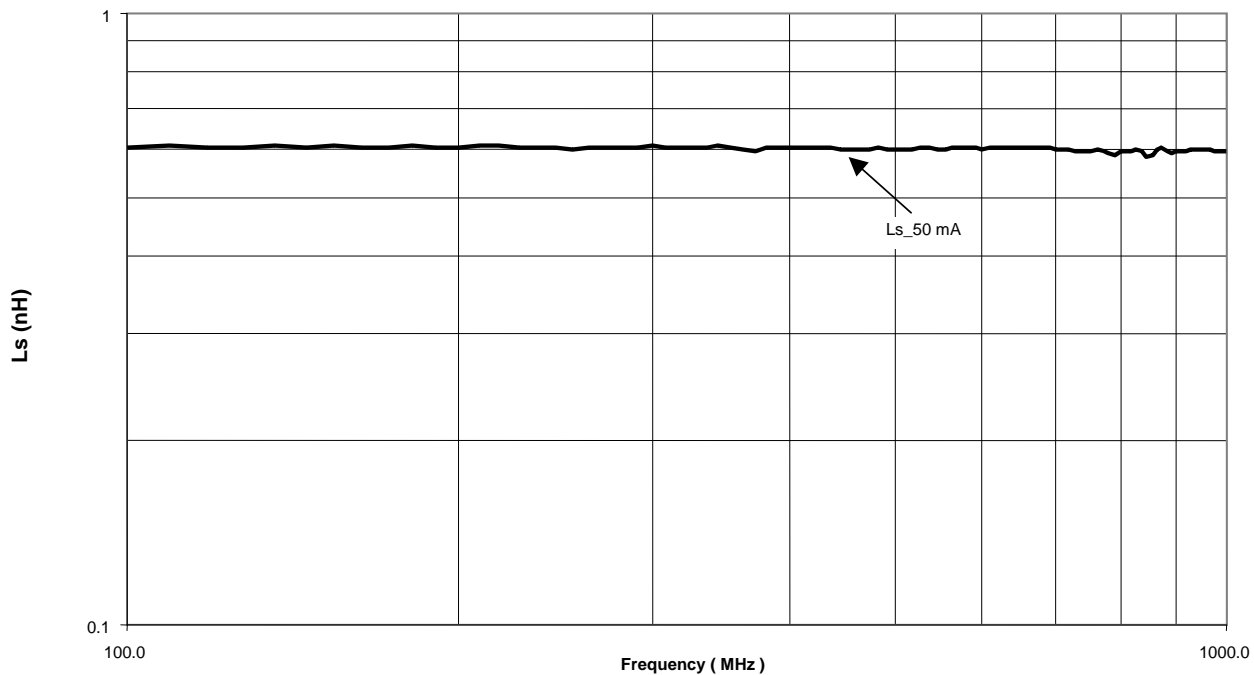


Typical Electrical Performance

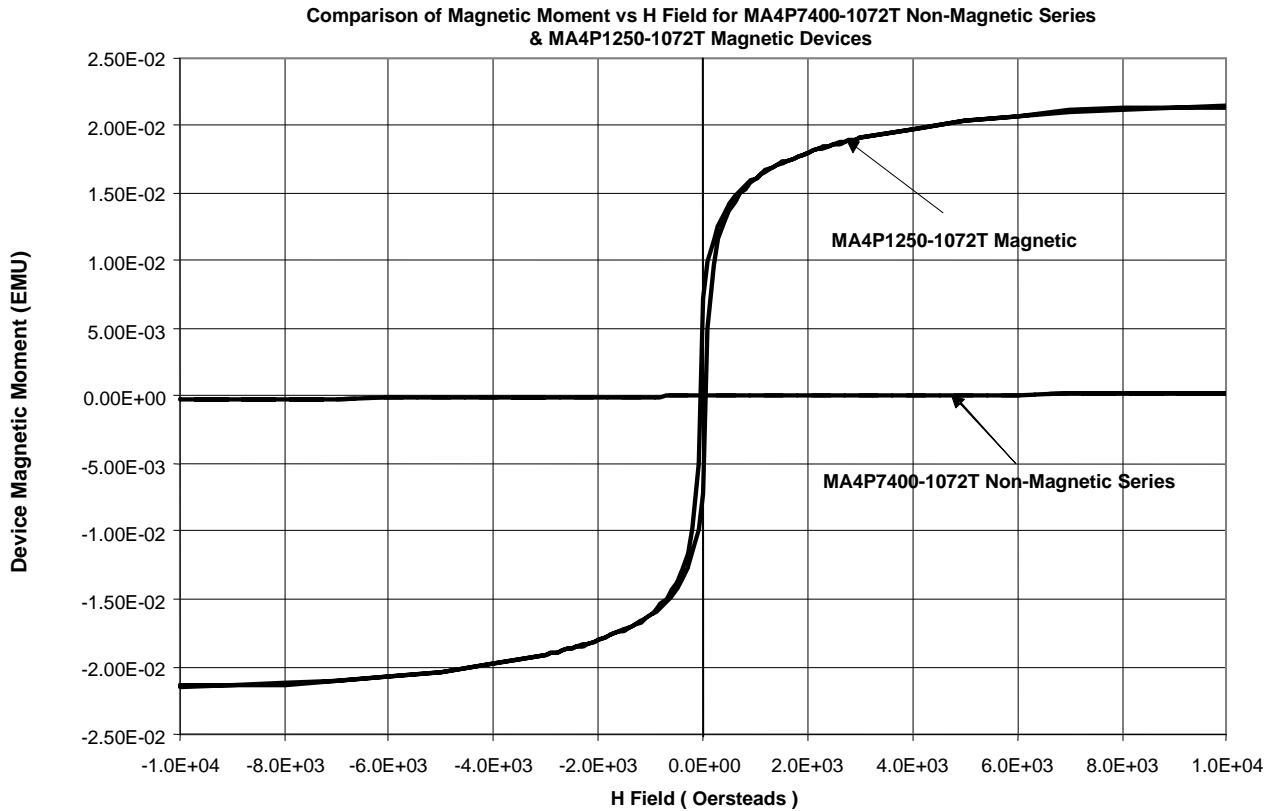
MA4P7470F-1072T Ct vs Voltage



MA4P7470F-1072T Ls vs Frequency



Typical Non-Magnetic Performance



**Table 1 - Typical Magnetic Properties of Non-Magnetic MA4P7470F-1072T Device
vs.
A Conventional MA4P1250-1072T Magnetic Device**

Magnetic Property	MA4P7470F-1072T Value	MA4P1250-1072T Value
Saturation Moment (EMU) @ H = H _{MAX} Oersteds	2.3 x E-4	2.1 x E-2
Remanance Moment (EMU) @ H = 0 Oersteds	4.2 x E-8	7.1 x E-3
Coercivity (Oersteds) @ EMU = 0 Moment	1	59.2



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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.